SK 95 DGL 126



3-phase bridge rectifier + brake chopper

SK 95 DGL 126

Target Data

Features

- Compact design
- · One screw mounting
- Heat transfer and isolation through direct copper bonded alumium oxide ceramic (DCB)
- Trench IGBT technology
- CAL Technology FWD

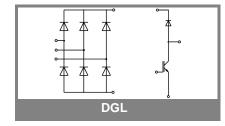
Typical Applications*

Rectifier

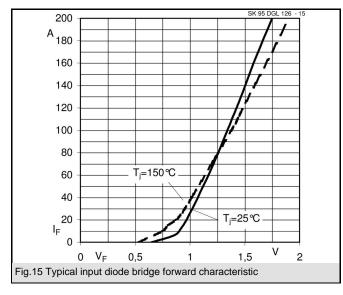


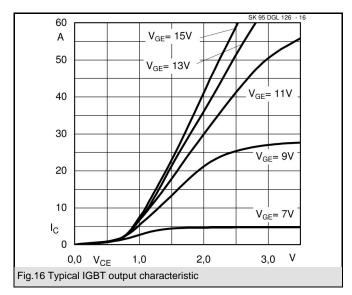
Absolute Maximum Ratings T _s = 25°C, unless otherwise specifie								
Symbol	Conditions	Values	Units					
IGBT - Chopper								
V_{CES}		1200	V					
I _C	T _s = 25 (80) °C	40 (32)	Α					
I _{CRM}	$I_{CRM} = 2 \times I_{Cnom}, t_p = 1 \text{ ms}$	70	Α					
V_{GES}		±20	V					
T _j		-40 + 150	°C					
Diode - Chopper								
I _F	T _s = 25 (80) °C	45 (35)	Α					
I _{FRM}	$I_{FRM} = 2xI_{Fnom}, t_p = 1 \text{ ms}$	100	Α					
T _j		-40 + 150	°C					
Rectifier								
V_{RRM}		1600	V					
I _D	T _s = 80 °C	96	Α					
I _{FSM} / I _{TSM}	$t_{p} = 10 \text{ ms}$, sin 180 °, $T_{i} = 25 \text{ °C}$	700	Α					
I ² t	t _p = 10 ms , sin 180 ° ,T _i = 25 °C	2450	A²s					
T _j	,	-40 + 150	°C					
T _{sol}	Terminals, 10s	260	°C					
T _{stg}		-40 + 125	°C					
V _{isol}	AC, 1 min. / 1s	2500 / 3000	V					

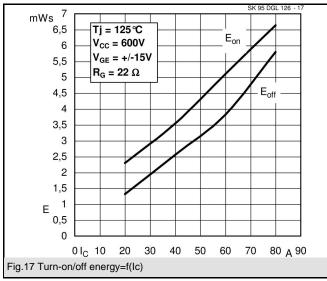
Characteristics		T _s = 25°C, unless otherwise specified						
Symbol	Conditions	min.	typ.	max.	Units			
IGBT - Chopper								
$\begin{matrix} V_{CEsat} \\ V_{GE(th)} \\ V_{CE(TO)} \\ r_{T} \\ C_{ies} \\ C_{oes} \end{matrix}$	$I_{C} = 35 \text{ A}, T_{j} = 25 (125) ^{\circ}\text{C}$ $V_{GE} = V_{CE}, I_{C} = 1,5 \text{ mA}$ $T_{j} = 25 ^{\circ}\text{C} (125) ^{\circ}\text{C}$ $T_{j} = 25 ^{\circ}\text{C} (125) ^{\circ}\text{C}$ $V_{CE} = 25 V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$	5	1,7 (2) 5,8 1 (0,9) 20 (31) 2,4 0,5 0,4	2,1 6,5 1,2 26	V V mΩ nF nF			
C _{res} R _{th(j-s)}	per IGBT		0,4	1,05	K/W			
$\begin{aligned} & \underset{t_{d(on)}}{\text{t}_{d(on)}} \\ & \underset{t_{r}}{t_{d(off)}} \\ & \underset{t_{r}}{t_{d(off)}} \\ & \underset{E_{on}}{E_{on}} \\ & \underset{C}{E_{off}} \\ & \\ & \underset{(TO)}{Diode - Cl} \\ & \underset{(TO)}{V_{F} = V_{EC}} \\ & \underset{(TO)}{V_{(TO)}} \\ & \underset{T_{RRM}}{T_{RRM}} \\ & \underset{C_{rr}}{Q_{rr}} \\ & \underset{E_{rr}}{E_{rr}} \end{aligned}$	under following conditions V_{CC} = 600 V, V_{GE} = ± 15 V I_{C} = 30 A, I_{T} = 125 °C I_{Gon} = I_{Gon} = 22 I_{Gon} inductive load		85 30 430 90 4,6 4,3 1,5 (1,5) (0,92) (13,4)	1,77 (1,77)	ns ns ns ns mJ mJ V V mΩ K/W A µC mJ			
Diode rectifier								
$V_{F} \\ V_{(TO)} \\ r_{T} \\ R_{th(j-s)}$	$I_F = 35 \text{ A}, T_j = 25(125) ^{\circ}\text{C}$ $T_j = 150 ^{\circ}\text{C}$ $T_j = 150 ^{\circ}\text{C}$ per diode		-	1,2 0,8 11 1,2	V V mΩ K/W			
Temperatur sensor								
R _{ts}	%, T _r = () °C		()		Ω			
Mechanical data								
w M _s	Mounting torque		30	2,5	g Nm			

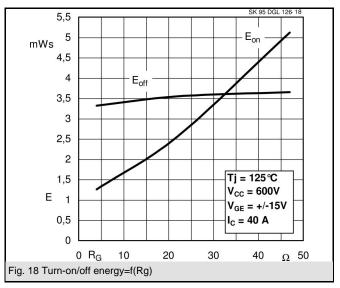


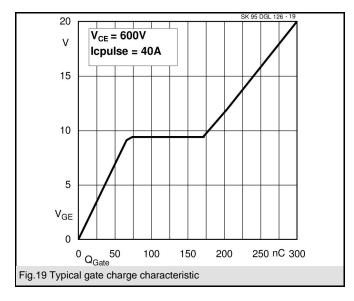
SK 95 DGL 126



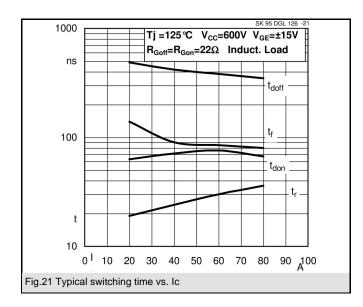


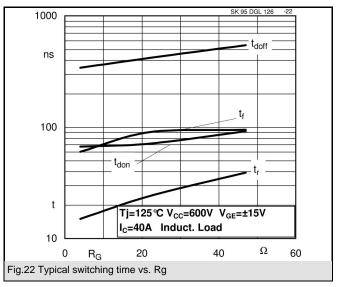


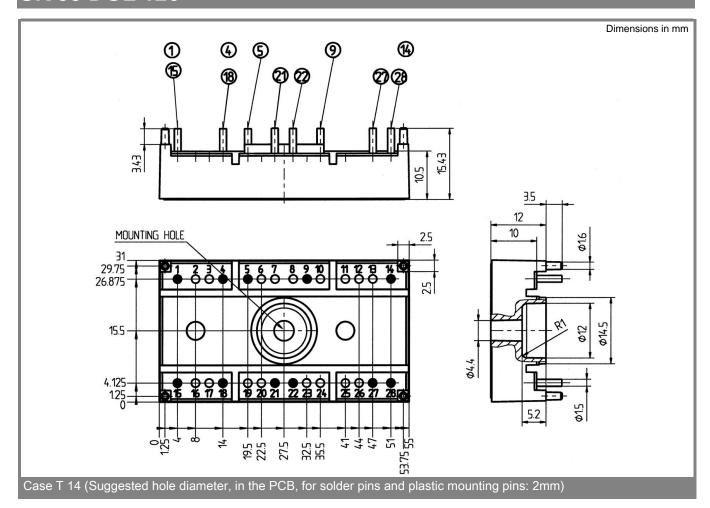


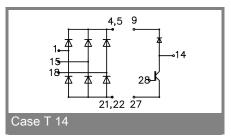


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This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.